

BYX96 SERIES

PHILIPS INTERNATIONAL

56E D ■ 7110826 0041652 1T3 ■ PHIN

T-01-19

RECTIFIER DIODES

Also available to BS9331-F129

Silicon rectifier diodes in metal envelopes similar to DO-4, intended for use in power rectifier applications.

The series consists of the following types:

Normal polarity (cathode to stud): BYX96-300 to 1600.

Reverse polarity (anode to stud): BYX96-300R to 1600R.

QUICK REFERENCE DATA

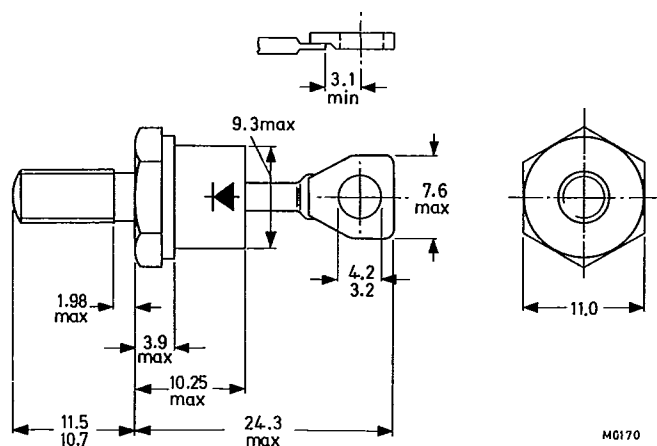
		BYX96-300(R)	600(R)	1200(R)	1600(R)	
Repetitive peak reverse voltage	V_{RRM}	max. 300	600	1200	1600	V
Average forward current	$I_{F(AV)}$		max.		30	A
Non-repetitive peak forward current	I_{FSM}		max.		400	A

MECHANICAL DATA

Dimensions in mm

Fig.1 DO-4: with metric M5 stud (ϕ 5 mm); e.g. BYX96-300(R).

Types with 10-32 UNF stud (ϕ 4,83 mm) are available on request. These are indicated by the suffix U; e.g. BYX96-300U(RU).



Supplied with device: 1 nut, 1 lock-washer

Nut dimensions across the flats, M5 thread: 8 mm, 10-32 UNF thread: 9.5 mm

Net mass: 7 g

Diameter of clearance hole: max. 5.2 mm

Supplied on request: see ACCESSORIES section
a version with insulated flying leads

The mark shown applies to normal polarity types.

Torque on nut: min. 0.9 Nm
(9 kg cm)
max. 1.7 Nm
(17 kg cm)

**BYX96
SERIES**

T-01-19

PHILIPS INTERNATIONAL

56E D ■ 7110826 0041653 03T ■ PHIN

RATINGS Limiting values in accordance with the Absolute Maximum System (IEC 134)

<u>Voltages</u> ¹⁾		BYX96-300(R)	600(R)	1200(R)	1600(R)	
Non-repetitive peak reverse voltage (t ≤ 10 ms)	V _{RSM}	max. 300	600	1200	1600	V
Repetitive peak reverse voltage (δ ≤ 0,01)	V _{RRM}	max. 300	600	1200	1600	V
Crest working reverse voltage	V _{RWM}	max. 200	400	800	800	V
Continuous reverse voltage	V _R	max. 200	400	800	800	V

Currents

Average forward current (averaged over any 20 ms period) up to T _{mb} = 125 °C	I _{F(AV)}	max.	30	A
R. M. S. forward current	I _{F(RMS)}	max.	48	A
Repetitive peak forward current	I _{FRM}	max.	400	A
Non-repetitive peak forward current (t = 10 ms; half sine-wave) T _j = 175 °C prior to surge; with reapplied V _{RWMmax}	I _{FSM}	max.	400	A
I ² t for fusing (t = 10 ms)	I ² t	max.	800	A ² s

Temperatures

Storage temperature	T _{stg}	-55 to +175	°C
Junction temperature	T _j	max. 175	°C

THERMAL RESISTANCE

From junction to mounting base	R _{th j-mb}	=	1,0	°C/W
From mounting base to heatsink without heatsink compound	R _{th mb-h}	=	0,5	°C/W
with heatsink compound	R _{th mb-h}	=	0,3	°C/W
Transient thermal impedance; t = 1 ms	Z _{th j-mb}	=	0,2	°C/W

¹⁾ To ensure thermal stability: R_{th j-a} ≤ 2 °C/W (continuous reverse voltage) or ≤ 8 °C/W (a.c.)

For smaller heatsinks T_{j max} should be derated. For a.c. see page 4.

For continuous reverse voltage: if R_{th j-a} = 4 °C/W, then T_{j max} = 138 °C,

if R_{th j-a} = 6 °C/W, then T_{j max} = 125 °C.

**BYX96
SERIES**

PHILIPS INTERNATIONAL

56E D ■ 7110826 0041654 T76 ■ PHIN

T-01-19

CHARACTERISTICS

Forward voltage

$$I_F = 100 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$$

$$V_F < 1,7 \text{ V } ^1)$$

Reverse current

$$V_R = V_{RWMmax}; T_j = 125 \text{ }^\circ\text{C}$$

$$I_R < 1 \text{ mA}$$

OPERATING NOTES

1. The top connector should neither be bent nor twisted; it should be soldered into the circuit so that there is no strain on it.
During soldering the heat conduction to the junction should be kept to a minimum.
2. Where there is a possibility that transients, due to the energy stored in the transformer, will exceed the maximum permissible non-repetitive peak reverse voltage, see General Section for information on damping circuits.

¹⁾ Measured under pulse conditions to avoid excessive dissipation.

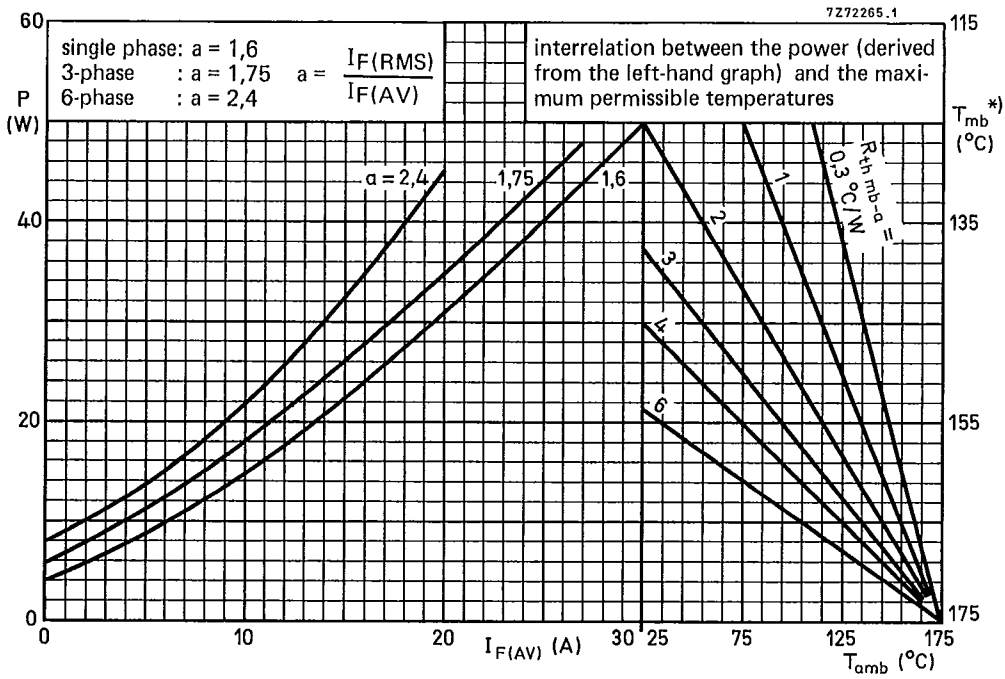
BYX96
SERIES

T-01-19

PHILIPS INTERNATIONAL

56E D

7110826 0041655 902 PHIN



*) T_{mb} -scale is for comparison purposes only and is correct only for $R_{th\ mb-a} \leq 6,5\ ^\circ C/W$

T-01-19

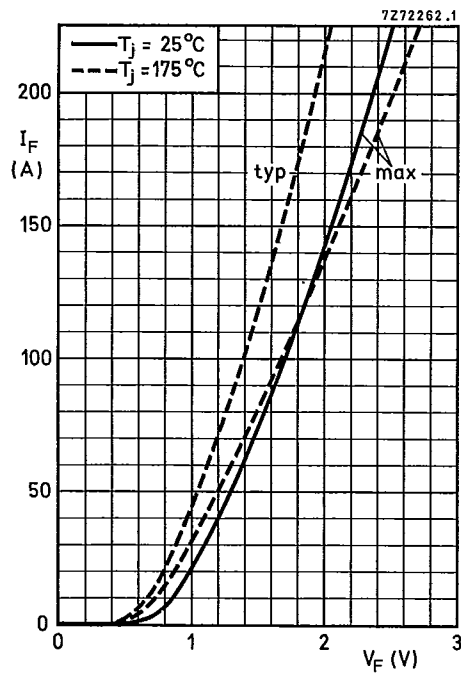
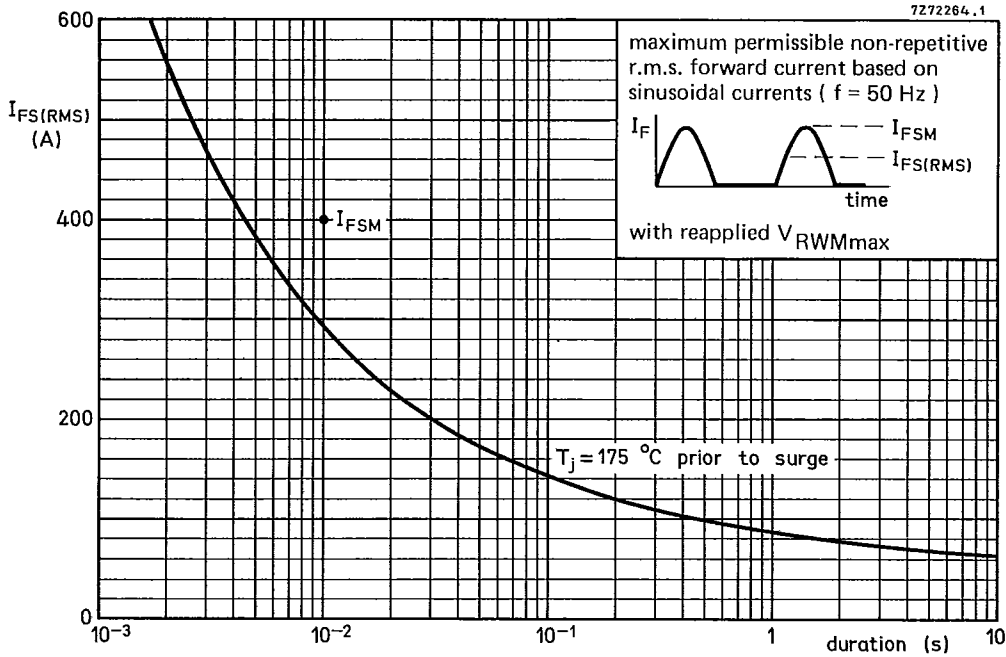
BYX96
SERIES

PHILIPS INTERNATIONAL

56E D

7110826 0041656 849

PHIN



BYX96
SERIES

T-01-19

PHILIPS INTERNATIONAL

56E D ■ 7110826 0041657 785 ■ PHIN

